

DUAL PRE-POWER AMPLIFIER WITH DC VOLUME CONTROL

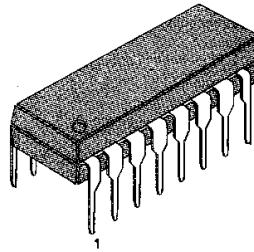
The KA22134 is a monolithic integrated circuit designed for use in low voltage and low power applications. It has all functions including a dual audio pre-power amplifier, DC volume control and headphone drive circuits.

It is suitable for portable tape recorders or headphone cassette recorders.

FEATURES

- Built-in DC volume control circuit.
- Wide operation supply voltage: $V_{CC} = 1.8 \sim 6V$
- Only a few components to build headphone cassette tape recorders.
- Built-in ripple filter.

16 DIP



BLOCK DIAGRAM

ORDERING INFORMATION

Device	Package	Operating Temperature
KA22134	16 DIP	-20°C ~ +75°C

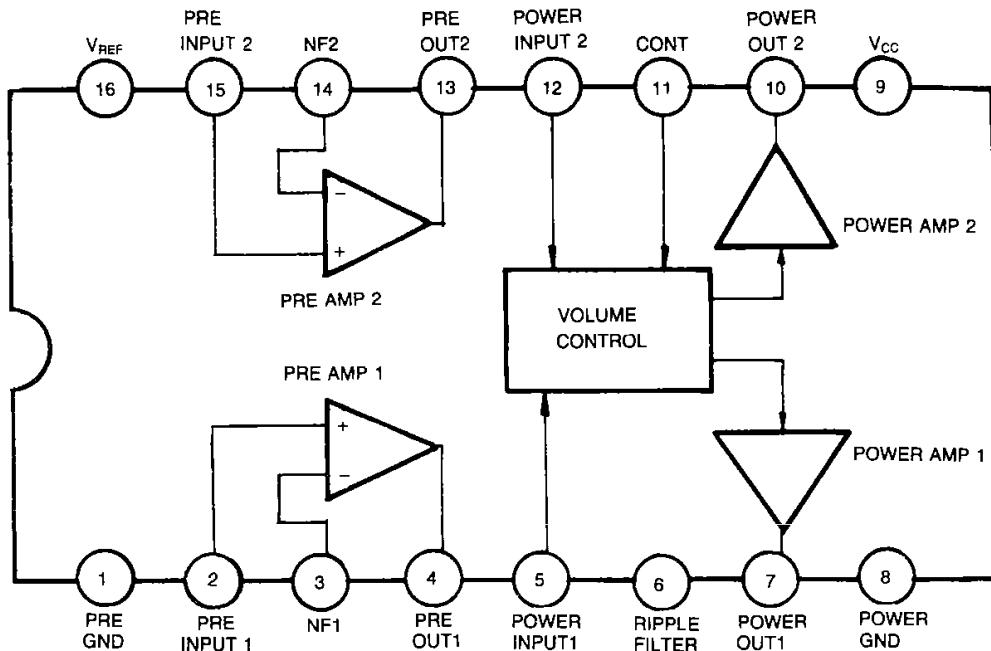


Fig. 1

ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ C$)

Characteristic	Symbol	Value	Unit
Supply Voltage	V_{CC}	7	V
Power Dissipation	P_D	75Ω	mW
Operating Temperature	T_{OPR}	-20 ~ +75	°C
Storage Temperature	T_{STG}	-40 ~ +125	°C

ELECTRICAL CHARACTERISTICS(V_{CC} = 3V, Ta = 25°C)

Characteristic	Symbol	Test Conditions	Min	Typ	Max	Unit
Quiescent Circuit Current	I _{CC01}	V _I = 0, V _{OL} = MIN		9	13	mA
	I _{CC02}	V _I = 0, V _{OL} = MAX		11.0		mA
Cross Talk	CT	R _G = 2.2KΩ, V _O = -10dBm	34	40		dB

PRE-AMPLIFIER SECTION(V_{CC} = 3V, Ta = 25°C, f = 1KHz, R_{L1} = 10KΩ, unless otherwise specified)

Characteristic	Symbol	Test Conditions	Min	Typ	Max	Unit
Open Loop Voltage Gain	G _{VO}	V _I = 0.2mV	55	62		dB
Closed Loop Voltage Gain	G _{VC1}	V _O = -10dBm, NAB 1KHz		33		dB
Output Voltage	V _O	THD = 1%	600	720		mV
Total Harmonic Distortion	THD ₁	V _O = -10dBm		0.04	0.1	%
Ripple Rejection Ratio	RR ₁	R _G = 2.2KΩ V _R = -20dBm, f _R = 100Hz		46		dB
Equivalent Input Noise Voltage	V _{NI}	R _G = 2.2KΩ, BW = 30 ~ 20KHz Gain for NAB 1KHz		1.2	2.0	μV

POWER AMPLIFIER SECTION(V_{CC} = 3V, Ta = 25°C, f = 1KHz, R_{L2} = 32Ω, unless otherwise specified)

Characteristic	Symbol	Test Conditions	Min	Typ	Max	Unit
Output Power	P _{O1}	THD ₂ = 10%	20	27		mW
	P _{O2}	THD ₂ = 10%, R _L = 16Ω		39		mW
Total Harmonic Distortion	THD ₂	P _O = 10mW, Volume: 100%		0.5	1.2	%
	THD ₃	P _O = 10mW, Volume: 50%		0.3		%
Closed Loop Voltage Gain	G _{VC2}	V _O = -10dBm, Volume: 100%	28	30	32	dB
	G _{VC3}	V _O = -10dBm		15		dB
Channel Balance	CB	V _O = -10dBm	-1.5	0	-1.5	dB
Volume Rejection Ratio	V _O _{REJ}	V _O = -10dBm, Volume: 100% to 0%	66	72		dB
Output Noise Voltage	V _{NO}	BW = 30 ~ 20KHz, R _G = 600Ω		250	320	μV
Ripple Rejection Ratio	RR ₂	R _G = 600Ω, f _R = 100Hz V _R = -20dBm		46		dB

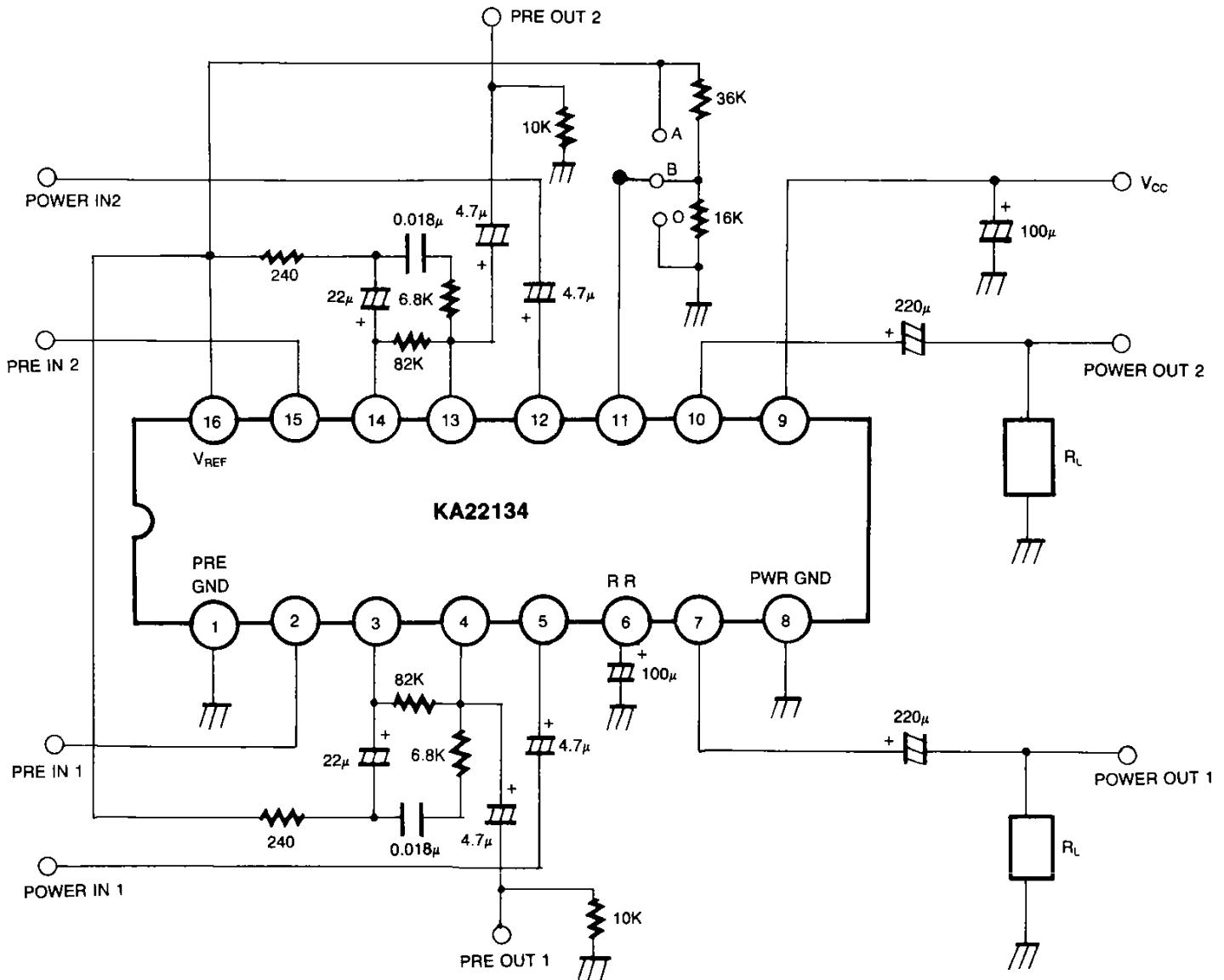
TEST CIRCUIT

Fig. 2

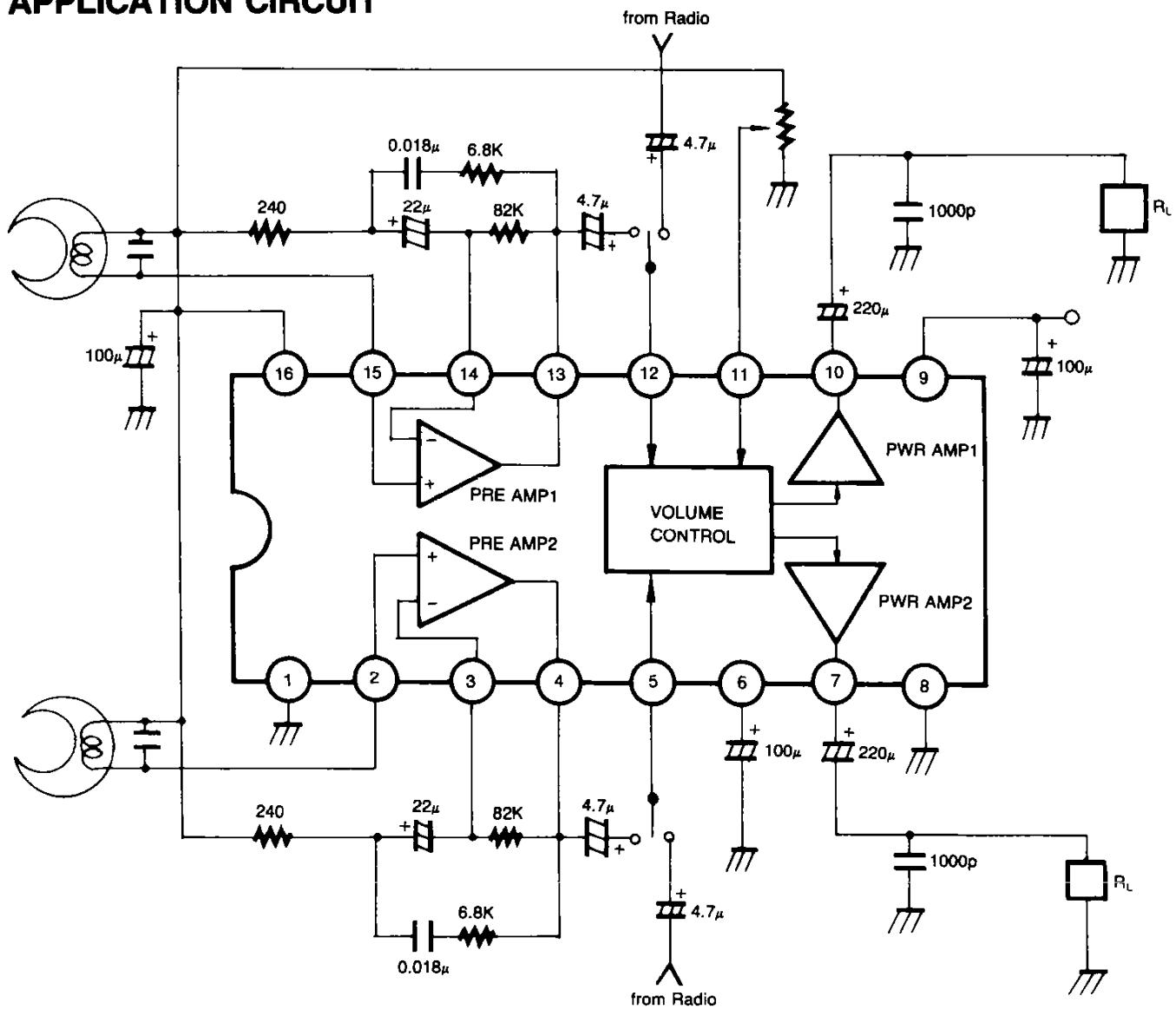
APPLICATION CIRCUIT

Fig. 3